



DONGGUAN NANJING ELECTRONICS LTD.,

MBF Plastic-Encapsulate Bridge Rectifier

MB22F THRU MB210F General Purpose Bridge Rectifier

Features

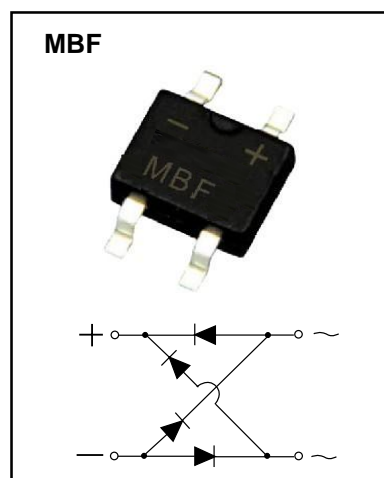
- $I_{F(AV)}$ 2A
- V_{RRM} 200V-1000V
- High surge current capability
- Glass passivated chip

Applications

- General purpose 1 phase Bridge rectifier applications

Marking

- MB2XF
X : From 2 To 10



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Conditions	MB				
				22F	24F	26F	28F	210F
Repetitive Peak Reverse Voltage	V_{RRM}	V		200	400	600	800	1000
Maximum RMS Voltage	V_{RMS}	V		140	280	420	560	700
Average Rectified Output Current	I_o	A	60Hz sine wave, R-load, $T_a=115^\circ\text{C}$	On alumina substrate		2.0		
Surge(Non-repetitive)Forward Current	I_{FSM}	A	8.3ms sine wave, 1 cycle, $T_j=25^\circ\text{C}$	55				
			1.0ms sine wave, 1 cycle, $T_j=25^\circ\text{C}$	75				
Current Squared Time	I^2t	A^2S	$1\text{ms} \leq t < 8.3\text{ms}$ $T_j=25^\circ\text{C}$, Rating of per diode		8.03			
Operation Junction and Storage Temperature Range	T_j, T_{stg}	$^\circ\text{C}$	-55 ~ +150					

Electrical Characteristics ($T=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	Max
Peak Forward Voltage	V_{FM}	V	$I_{FM}=1.0\text{A}$, Pulse measurement, Rating of per diode	0.95
Peak Reverse Current	I_{RRM}	μA	$V_{RM}=V_{RRM}$, Pulse measurement, Rating of per diode	5
Thermal Resistance	$R_{\theta J-A}$	$^\circ\text{C/W}$	Between junction and ambient, On alumina substrate	25
	$R_{\theta J-L}$		Between junction and lead	18
	$R_{\theta J-C}$		Between junction and case	18

Typical Characteristics

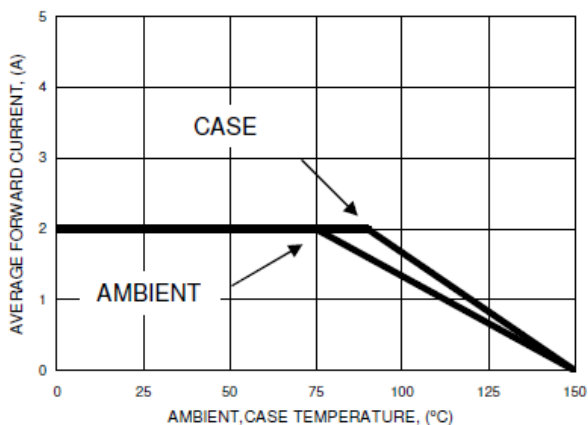


FIG.1- FORWARD CURRENT DERATING CURVE

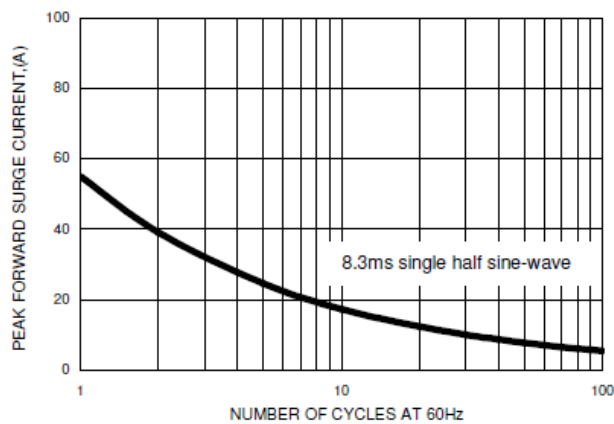


FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

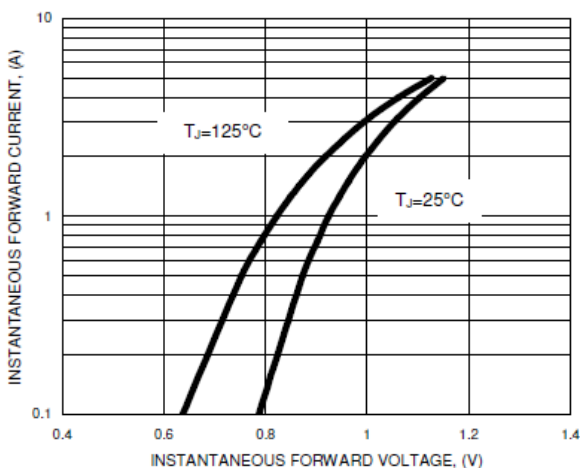


FIG.3- TYPICAL FORWARD CHARACTERISTICS

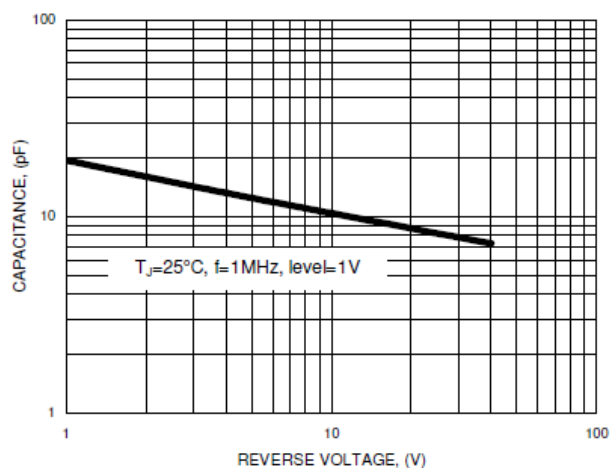


FIG.4- TYPICAL JUNCTION CAPACITANCE

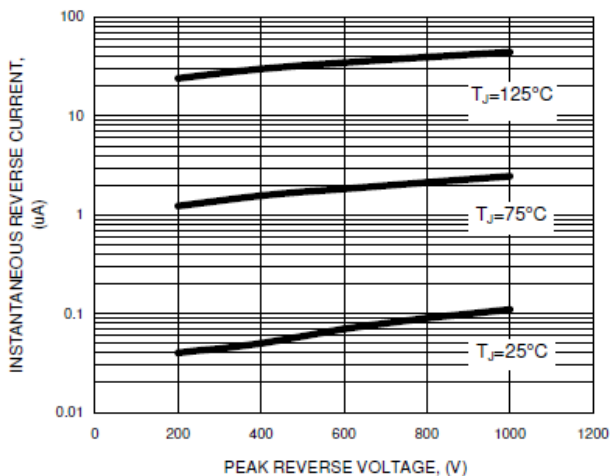
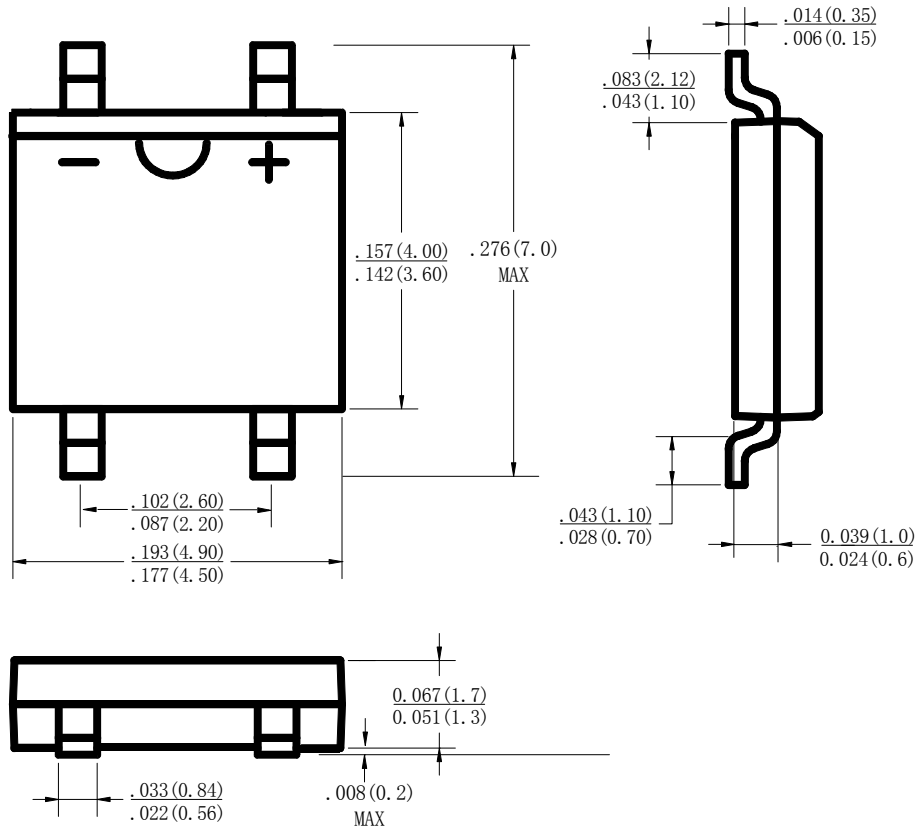


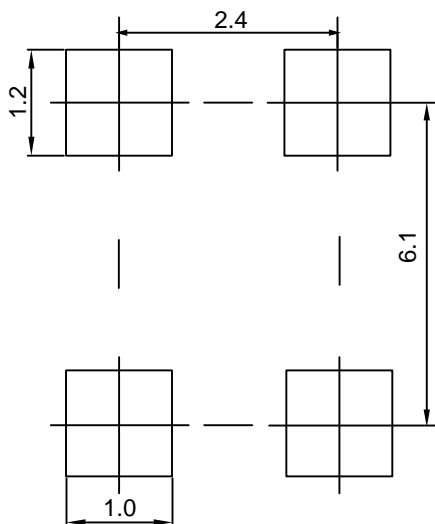
FIG.5- TYPICAL REVERSE CHARACTERISTICS

MBF Package Outline Dimensions



Dimensions in inches and (millimeters)

MBF Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

Reel Taping Specifications For Surface Mount Devices-MBF

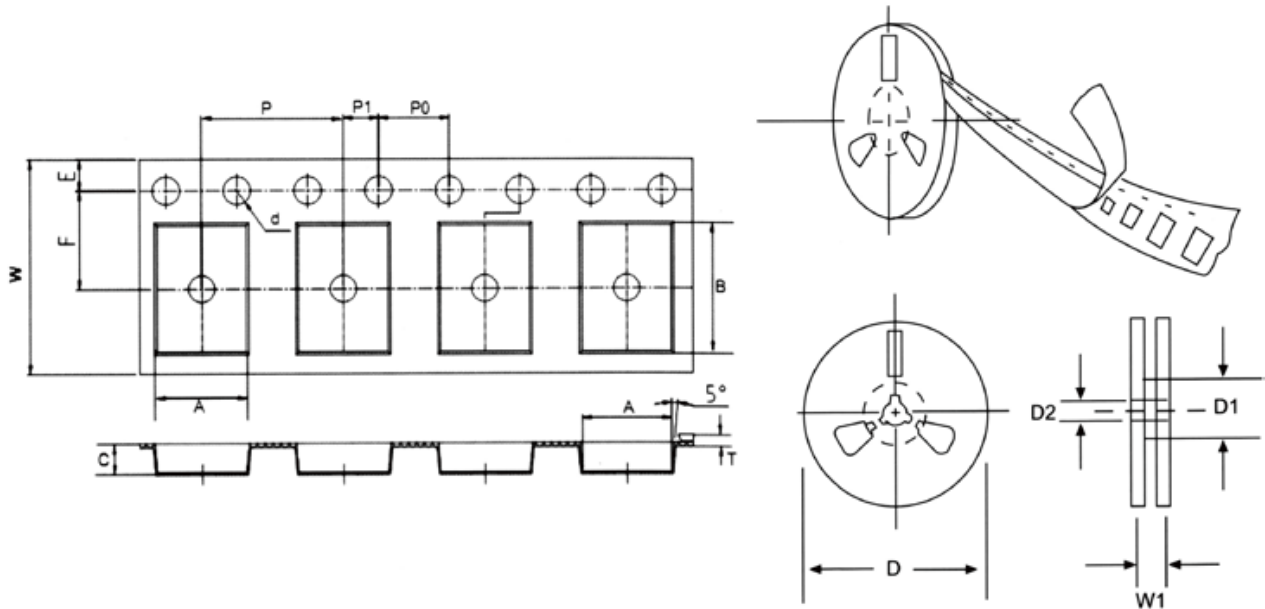


FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING

ITEM	SYMBOL	MBF mm(inch)
Carrier width	A	5.02+0.1(0.198+0.004)
Carrier length	B	7.15+0.1(0.281+0.004)
Carrier depth	C	1.65+0.1(0.074+0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	279±2.0 (11± 0.079)
Reel inner diameter	D1	75 ±1.0 (2.95 ±0.039)
Feed hole diameter	D2	13+0.5(0.512+0.020)
Strocket hole position	E	1.75+0.1(0.069+0.004)
Punch hole position	F	5.50+0.1(0.217+0.002)
Punch hole pitch	P	8.0+0.1(0.315+0.004)
Sprocket hole pitch	P0	4.0+0.1(0.157+0.004)
Embossment center	P1	2.0+0.1(0.079+0.004)
Total tape thickness	T	0.20-0.70(0.008-0.028)
Tape width	W	12.0+0.3/-0.1(0.472+0.004)
Reel width	W1	16.8+2.0(0.661+0.079)

NOTE: Devices are packde in accordance with EIA standard RS-481-A and specification given above.